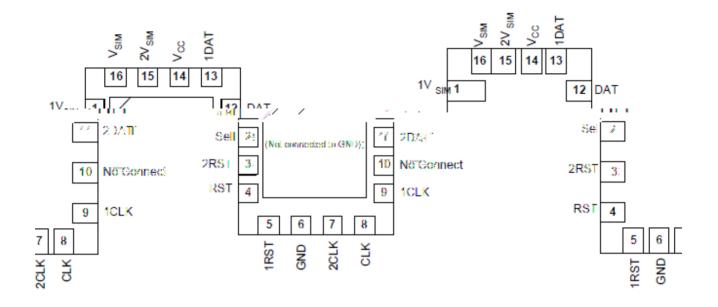
# BCT4567 Low-Power, Dual SIM Card Analog Switch

### **GENERAL DESCRIPTION**

The BCT4567 is a quad-SPDT switch with one common control inputs targeted at dual SIM

### **Pin Configurations**



### **Pin Description**

Pin	Name	Function
1	1VSIM	SIM supply output 2
2	SEL	Select input
3	2RST	RST Normally Open Terminal
4	RST	RST Common Terminal
5	1RST	RST Normally Closed Terminal
6	GND	Ground
7	2CLK	CLK Normally Open Terminal
8	CLK	CLK Common Terminal
9	1CLK	CLK Normally Closed Terminal
10	NC	Not Connect
11	2DAT	DAT Normally Open Terminal
12	DAT	DAT Common Terminal
13	1DAT	DAT Normally Closed Terminal
14	VCC	Power Supply
15	2VSIM	SIM supply output 1
16	VSIM	SIM supply input

### **Truth Table**

SEL	SWITCH STATE	
0 1DAT = DAT, 1RST = RST, 1CLK = CLK, 1V <sub>SIM</sub> = V <sub>SIM</sub>		
1	2DAT = DAT, 2RST = RST, 2CLK = CLK, 2V <sub>SIM</sub> = V <sub>SIM</sub>	

### **Absolute Maximum Ratings**

VCC, SEL to GND	-0.3V to +6.0V
All Other Pins to GND	0.3V to (VCC + 0.3V)
Continuous Current	±400mA
Peak Current (pulsed at 1ms, 10% duty cyc	le)±500mA
Continuous Power Dissipation (TA = +70°C)	) ( 15.6mW/°C above +70°C)1.25W
Operating Temperature Range	40°C to +85°C
	65°C to +150°C
Junction 01(C)]TJETT BT1.0303 0 0 1 410.	26 465462.55 Tm[ )]TJET EMC /P

### **Electrical Characteristics (continued)**

(unless otherwise noted. Typical values are at VCC = 3.3V, TA = +25°C.) (2)

Parameter	Symbol	Conditions		Min	Тур	Max	Units	
DYNAMIC CHARACTERISTICS								
Turn-On Time Sel to Output	Ton	Pf, VSW = 1.5 V,	T <sub>A</sub> = +25°C		20	30		
(DAT,CLK,RST)	TON	Figure 11, Figure 12	$T_A = T_{MIN}$ to $T_{MAX}$			50	ns	
Turn-Off Time Sel to Output	Toff	pF, VSW = 1.5 V, Figure 11, Figure 12	T <sub>A</sub> = +25°C		15	40		
(DAT,CLK,RST)			$T_A = T_{MIN} to$ $T_{MAX}$			50	ns	
Break-Before-Make	tввм	35 pF V <sub>SW1</sub> =	T <sub>A</sub> = +25°C	2	15			
Time (DAT,CLK,RST)	toom		$T_A = T_{MIN}$ to $T_{MAX}$	2			ns	
Charge Injection	Q	$C_L = 50 \text{ pF}, R_{GEN}$	<sub>GEN</sub> = 0 V		100		рС	
On-Channel Bandwidth -3dB (DAT,CLK,RST)	BW	R <sub>L</sub> L= 5 pF Figure 16			100		MHz	
Off-Isolation (DAT,CLK,RST)	Viso	R <sub>L</sub> 0KHz Figure 17			-66		dB	
Crosstalk	Vст	R <sub>L</sub> 0KHz Figure 18			-86		dB	
RST, CLK, DAT Off Capacitance	Coff	V <sub>CC</sub> = 3.3 V, Figure 19			30		pF	
RST, CLK, DAT On Capacitance	Con	V <sub>CC</sub> = 3.3 V, f = 1 MHz Figure 20			100		pF	

Note 2: Devices are 100% tested at TA = +25°C. Limits across the full temperature range are guaranteed by design and correlation.

#### **Test Diagrams / Timing Diagrams**

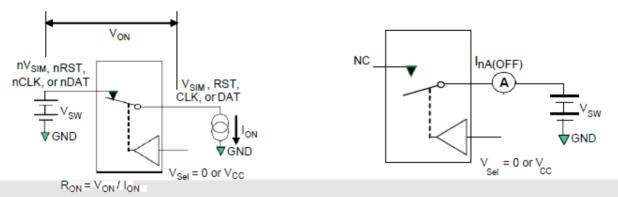
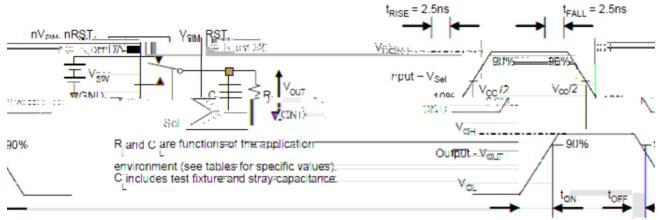


Figure 9. On Resistance

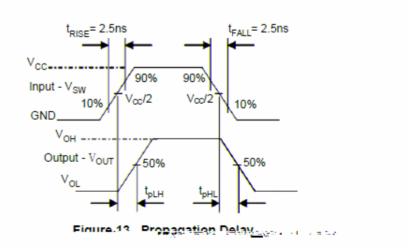
Figure 10. Off Leakage



forms

Figure 11. AC Test Circuit Load

Figure 12. Turn-On / Turn-Off Wave



### **Test Diagrams / Timing Diagrams**

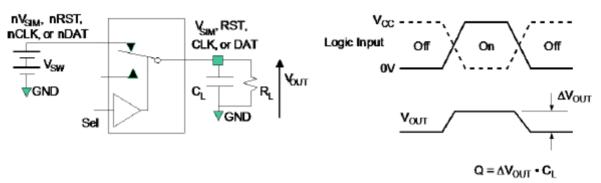
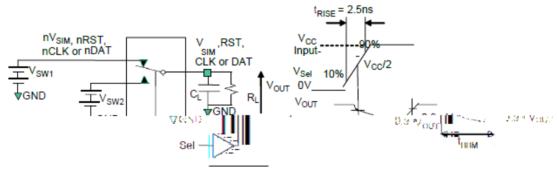
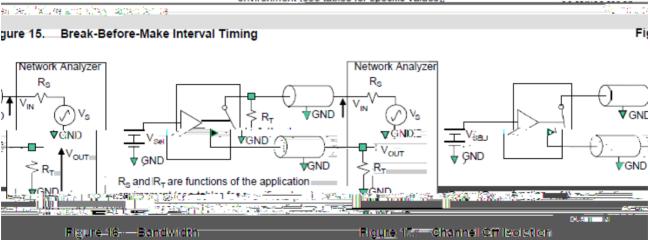


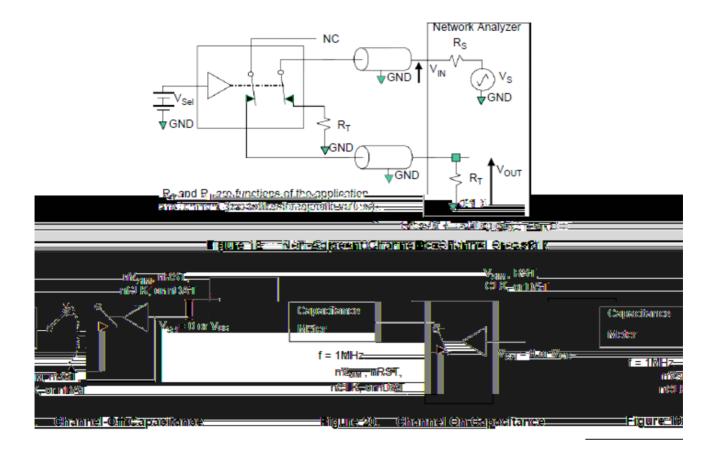
Figure 14. Charge Injection



R<sub>L</sub> and C<sub>L</sub> are functions of the application environment (see tables for specific values)



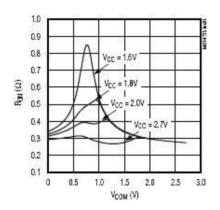
### **Test Diagrams / Timing Diagrams**



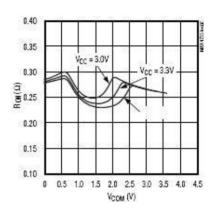
### **Typical Operating Characteristics**

(VCC = 3V, TA = +25°C, unless otherwise noted.)

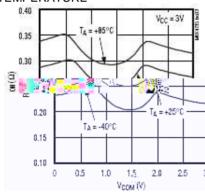
ON-RESISTANCE vs. COM\_ VOLTAGE



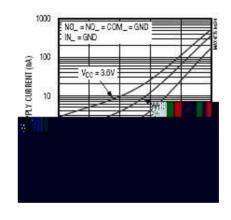
ON-RESISTANCE vs. COM\_ VOLTAGE



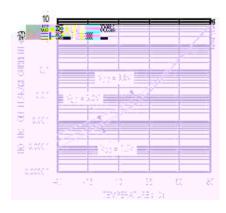
ON-RESISTANCE vs. COM\_ VOLTAGE AND TEMPERATURE



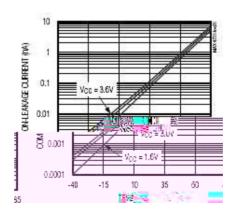
SUPPLY CURRENT vs. TEMPERATURE



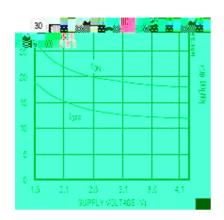
NO /NC OFF-LEAKAGE CURRENT vs. TEMPERATURE



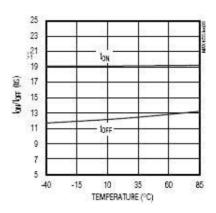
COM ON-LEAKAGE CURRENT vs. TEMPERATURE



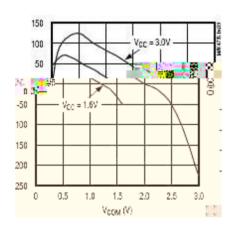
#### TURN-ON/OFF TIME vs. SUPPLY VOLTAGE



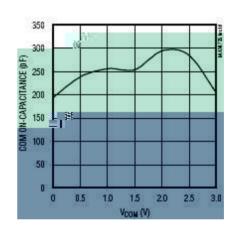
#### TURN-ON/OFF TIME vs. TEMPERATURE



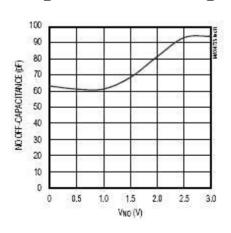
CHARGE INJECTION vs. COM\_ VOLTAGE



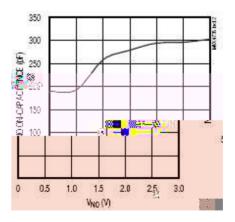
COM\_ ON-CAPACITANCE vs. COM\_ VOLTAGE



NO\_ OFF-CAPACITANCE vs. NO\_ VOLTAGE

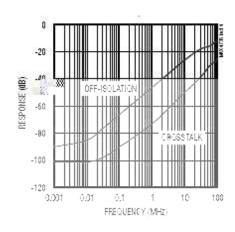


NO\_ ON-CAPACITANCE vs. NO\_ VOLTAGE

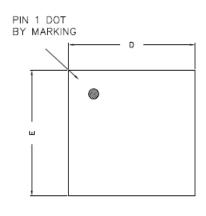


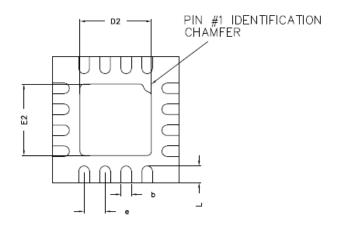
#### ON-RESPONSE vs. FREQUENCY

#### OFF-ISOLATION AND CROSSTALK vs. FREQUENCY



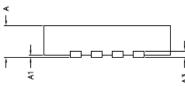
### PACKAGE OUTLINE DIMENSIONS: TQFN 3x3 -16L





TOP VIEW

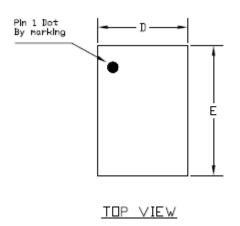
BOTTOM VIEW

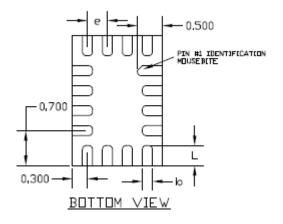


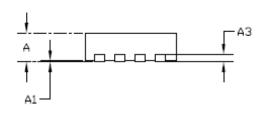
SIDE VIEW

COMMON DIMENSIONS(MM)					
PKG.	W: VERY VERY THIN				
REF.	MIN.	NOM.	MAX		
Α	0.70	0.75	0.80		
A1	0.00	-	0.05		
А3	0.2 REF.				
D	2.95	3.00	3.05		
E	2.95	3.00	3.05		
b	0.18	0.25	0.30		
L	0.30	0.40	0.50		
D2	1.55	1.70	1.80		
E2	1.55	1.70	1.80		
е	0.5 BSC				

### PACKAGE OUTLINE DIMENSIONS: UTQFN 1.8x2.6 -16L







SIDE VIEW

COMMON DIMENSIONS(MM)					
PKG.	UT:ULTRA THIN				
REF.	MIN.	N□M.	MAX		
Α	>0,50	0.55	0.60		
A1	0.00	-	0.05		
A3	0.15 RFF.				
D	1,75	1.80	1,85		
E	2,55	2.60	2,65		
L	0.30	0.40	0.50		
ь	0.15	0.20	0,25		
6	0.40 BSC				